Complementary ThermalTrak™ Transistors

The ThermalTrak family of devices has been designed to eliminate thermal equilibrium lag time and bias trimming in audio amplifier applications. They can also be used in other applications as transistor die protection devices.

Features

- Thermally Matched Bias Diode
- Instant Thermal Bias Tracking
- Absolute Thermal Integrity
- High Safe Operating Area
- Pb-Free Packages are Available*

Benefits

- Eliminates Thermal Equilibrium Lag Time and Bias Trimming
- Superior Sound Quality Through Improved Dynamic Temperature Response
- Significantly Improved Bias Stability
- Simplified Assembly
 - Reduced Labor Costs
 - Reduced Component Count
- High Reliability

Applications

- High-End Consumer Audio Products
 - Home Amplifiers
 - Home Receivers
- Professional Audio Amplifiers
 - Theater and Stadium Sound Systems
 - Public Address Systems (PAs)



ON Semiconductor®

http://onsemi.com

BIPOLAR POWER TRANSISTORS 15 AMP, 350 VOLT, 230 WATT

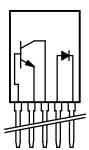


TO-264, 5 LEAD CASE 340AA STYLE 1

MARKING DIAGRAM

SCHEMATIC





NJLxxxxD = Device Code

xxxx = 4281 or 4302

G = Pb-Free Package A = Assembly Location

YY = Year WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping
NJL4281D	TO-264	25 Units / Rail
NJL4281DG	TO-264 (Pb-Free)	25 Units / Rail
NJL4302D	TO-264	25 Units / Rail
NJL4302DG	TO-264 (Pb-Free)	25 Units / Rail

^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MAXIMUM RATINGS ($T_J = 25^{\circ}C$ unless otherwise noted)

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V _{CEO}	350	Vdc
Collector–Base Voltage	V_{CBO}	350	Vdc
Emitter-Base Voltage	V_{EBO}	5	Vdc
Collector–Emitter Voltage – 1.5 V	V _{CEX}	350	Vdc
Collector Current – Continuous – Peak (Note 1)	I _C	15 30	Adc
Base Current – Continuous	l _Β	1.5	Adc
Total Power Dissipation @ T _C = 25°C Derate Above 25°C	P _D	230 1.84	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	- 65 to +150	°C
DC Blocking Voltage	V _R	200	V
Average Rectified Forward Current	I _{F(AV)}	1.0	Α

THERMAL CHARACTERISTICS

Characteristic		Max	Unit
Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	0.54	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

ATTRIBUTES

Characteristic		Value	
ESD Protection	Human Body Model Machine Model	>8000 V > 400 V	
Flammability Rating		UL 94 V-0 @ 0.125 in	

^{1.} Pulse Test: Pulse Width = 5 ms, Duty Cycle < 10%.

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS		1		
Collector Emitter Sustaining Voltage $(I_C = 50 \text{ mA}, I_B = 0)$	V _{CE(sus)}	350	_	Vdc
Collector Cut-off Current $(V_{CE} = 200 \text{ V}, I_B = 0)$	ICEO	_	100	μAdc
Collector Cutoff Current (V _{CB} = 350 Vdc, I _E = 0)	Ісво	_	50	μAdc
Emitter Cutoff Current $(V_{EB} = 5.0 \text{ Vdc}, I_C = 0)$	I _{EBO}	_	5.0	μAdc
SECOND BREAKDOWN				
Second Breakdown Collector with Base Forward Biased (V _{CE} = 50 Vdc, t = 1.0 s (non–repetitive) (V _{CE} = 100 Vdc, t = 1.0 s (non–repetitive)	I _{S/b}	4.5 1.0	- -	Adc
ON CHARACTERISTICS				
DC Current Gain $ \begin{aligned} &(I_C = 100 \text{ mAdc, V}_{CE} = 5.0 \text{ Vdc}) \\ &(I_C = 1.0 \text{ Adc, V}_{CE} = 5.0 \text{ Vdc}) \\ &(I_C = 3.0 \text{ Adc, V}_{CE} = 5.0 \text{ Vdc}) \\ &(I_C = 3.0 \text{ Adc, V}_{CE} = 5.0 \text{ Vdc}) \\ &(I_C = 5.0 \text{ Adc, V}_{CE} = 5.0 \text{ Vdc}) \\ &(I_C = 8.0 \text{ Adc, V}_{CE} = 5.0 \text{ Vdc}) \\ &(I_C = 15 \text{ Adc, V}_{CE} = 5.0 \text{ Vdc}) \end{aligned} $	h _{FE}	80 80 80 80 40	250 250 250 250 250 –	-
Collector–Emitter Saturation Voltage (I _C = 8.0 Adc, I _B = 0.8 Adc)	V _{CE(sat)}	-	1.0	Vdc
Emitter–Base Saturation Voltage ($I_C = 8.0 \text{ Adc}, I_B = 0.8 \text{ A}$)	V _{BE(sat)}	_	1.4	Vdc
Base–Emitter ON Voltage (I _C = 8.0 Adc, V _{CE} = 5.0 Vdc)	V _{BE(on)}	-	1.5	Vdc
DYNAMIC CHARACTERISTICS	·			
Current-Gain – Bandwidth Product (I _C = 1.0 Adc, V _{CE} = 5.0 Vdc, f _{test} = 1.0 MHz)	f _T	35	_	MHz
Output Capacitance ($V_{CB} = 10 \text{ Vdc}$, $I_E = 0$, $f_{test} = 1.0 \text{ MHz}$)	C _{ob}	_	600	pF
Maximum Instantaneous Forward Voltage (Note 2) $(i_F = 1.0 \text{ A}, T_J = 25^{\circ}\text{C})$ $(i_F = 1.0 \text{ A}, T_J = 150^{\circ}\text{C})$	VF	1.1 0.93		V
Maximum Instantaneous Reverse Current (Note 2) (Rated dc Voltage, $T_J = 25^{\circ}C$) (Rated dc Voltage, $T_J = 150^{\circ}C$)	i _R	10 100		μΑ
Maximum Reverse Recovery Time $(i_F = 1.0 \text{ A, di/dt} = 50 \text{ A/}\mu\text{s})$	t _{rr}	1	00	ns

^{2.} Diode Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

TYPICAL CHARACTERISTICS

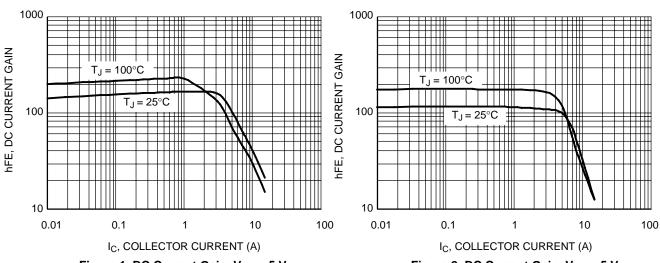


Figure 1. DC Current Gain, $V_{CE} = 5 \text{ V}$, NPN NJL4281D

Figure 2. DC Current Gain, V_{CE} = 5 V, PNP NJL4302D

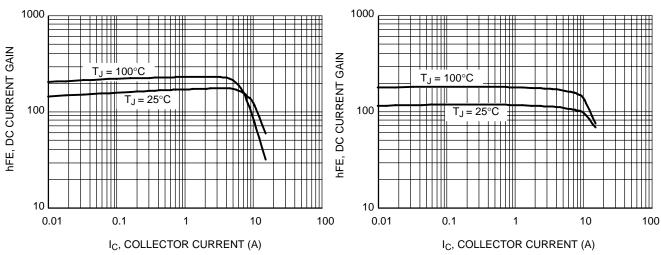


Figure 3. DC Current Gain, V_{CE} = 20 V, NPN NJL4281D

Figure 4. DC Current Gain, V_{CE} = 20 V, PNP NJL4302D

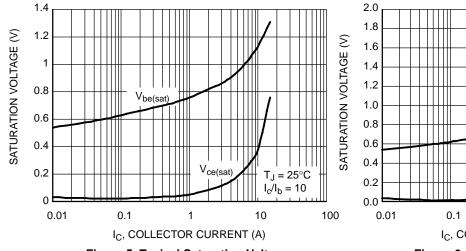


Figure 5. Typical Saturation Voltage, NPN NJL4281D

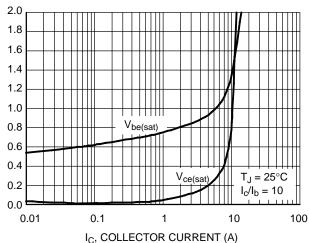


Figure 6. Typical Saturation Voltage, PNP NJL4302D

TYPICAL CHARACTERISTICS

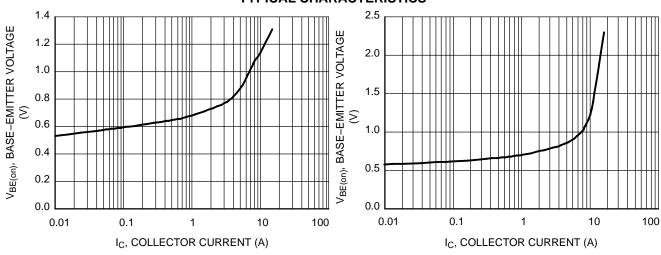


Figure 7. Typical Base–Emitter Voltages, NPN NJL4281D

Figure 8. Typical Base-Emitter Voltages, PNP NJL4302D

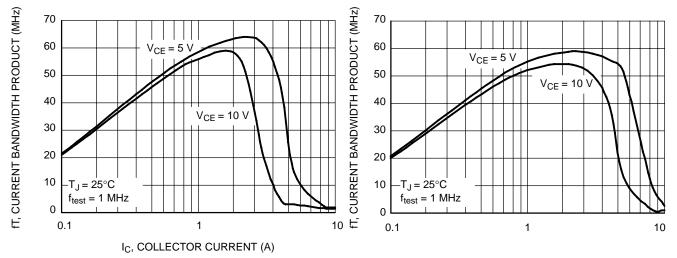


Figure 9. Typical Current Gain Bandwidth Product, NPN NJL4281D

Figure 10. Typical Current Gain Bandwidth Product, PNP NJL4302D

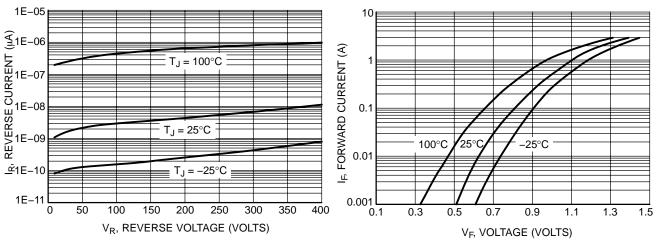


Figure 11. Typical Diode Reverse Current

Figure 12. Typical Diode Forward Voltage

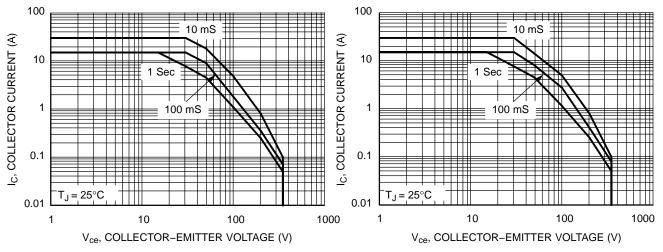
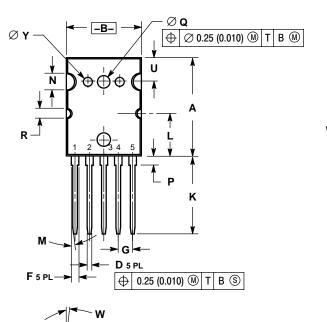


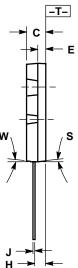
Figure 13. Active Region Safe Operating Area, NPN NJL4281D

Figure 14. Active Region Safe Operating Area, PNP NJL4302D

PACKAGE DIMENSIONS

TO-264, 5 LEAD CASE 340AA-01 **ISSUE O**





MILLIMETERS INCHES DIM MIN NOM MAX MIN NOM MAX 25.857 25.984 26.111 19.761 19.888 20.015 0.778 0.783 0.788 4.928 5.055 5.182 0.194 0.199 0.204 0.0480 BS D 1.219 BSC 2.032 2.108 2.184 0.0800 0.0830 0.0860 2.108 1 981 BS0 0.0780 BS 0.150 BS G 3.81 BS0 Н 2.667 2.718 2.769 0.1050 0.1070 0.1090 0.0230 BSC 0.584 BSC 0.804 0.809 0.814 0.444 REF K 20.422 20.549 20.676 L M 11.28 REF 4.57 REF 0.180 REF N 0.0889 0.0939 0.0989 2.386 2.513 Q 0.1370 BSC 3,480 BSC R 0.100 REF 2.54 REF W Y 0.243 REF 6.17 REF 0 ° - 6° _6 ° 0.0940 BS0

DIMENSIONING AND TOLERANCING PER

CONTROLLING DIMENSION: MILLIMETER.

STYLE 1:

NOTES

ANSI Y14.5M, 1982

- PIN 1. BASE 2. EMITTER
 - 3. COLLECTOR 4. ANODE

 - CATHODE

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